Unit: mm

TOSHIBA Transistor Silicon PNP Epitaxial Type (PCT Process)

### HN2A01FU

#### Audio Frequency General Purpose Amplifier Applications

• Small package (dual type)

• High voltage and high current :  $V_{CEO} = -50V$ ,  $I_C = -150 \text{mA}$  (max)

• High h<sub>FE</sub> :  $h_{FE} = 120 \sim 400$ 

• Excellent hFE linearity : hFE (IC = -0.1 mA) / (IC = -2 mA)

= 0.95 (typ.)

## Absolute Maximum Ratings (Ta = 25°C) (Q1, Q2 Common)

Characteristic	Symbol	Rating	Unit
Collector-base voltage	V <sub>CBO</sub>	-50	V
Collector-emitter voltage	V <sub>CEO</sub>	-50	V
Emitter-base voltage	V <sub>EBO</sub>	-5	V
Collector current	IC	-150	mA
Base current	ΙB	-30	mA
Collector power dissipation	P <sub>C</sub> *	200	mW
Junction temperature	Tj	125	°C
Storage temperature range	T <sub>stg</sub>	-55~125	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the

 $2.1 \pm 0.1$  $1.25 \pm 0.1$  $1.3\pm0.1$  $2.0 \pm 0.2$ 1. EMITTER 1 (E1) 2. EMITTER 2 (E2)3. BASE 2 (B2) 4. COLLECTOR 2 (C2) 5. BASE 1 (B1) 6. COLLECTOR 1 (C1) **JEDEC** EIAJ TOSHIBA 2-2J1B

Weight: 6.8mg

reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

#### Electrical Characteristics (Ta = 25°C) (Q1, Q2 Common)

Characteristic	Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I <sub>CBO</sub>	_	$V_{CB} = -50V, I_{E} = 0$	_	_	-0.1	μA
Emitter cut-off current	I <sub>EBO</sub>	_	$V_{EB} = -5V$ , $I_C = 0$	_	_	-0.1	μA
DC current gain	h <sub>FE</sub> (Note)	_	$V_{CE} = -6V, I_{C} = -2mA$	120	_	400	_
Collector-emitter saturation voltage	V <sub>CE</sub> (sat)	_	I <sub>C</sub> = -100mA, I <sub>B</sub> = -10mA	_	-0.1	-0.3	٧
Transition frequency	f <sub>T</sub>	_	V <sub>CE</sub> = −10V, I <sub>C</sub> = −1mA	80	_	_	MHz
Collector output capacitance	C <sub>ob</sub>	_	$V_{CB} = -10V$ , $I_E = 0$ , $f = 1MH_z$	_	4	7	pF

Note: hFE classification

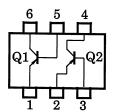
Y(Y): 120~240, GR(G): 200~400

() marking symbol

#### Marking

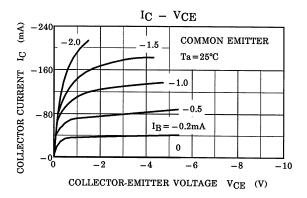
# Type Name hFE Rank

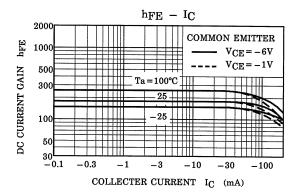
#### **Equivalent Circuit (Top View)**

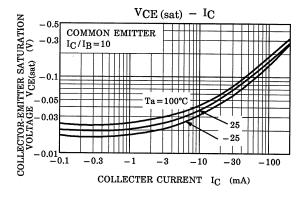


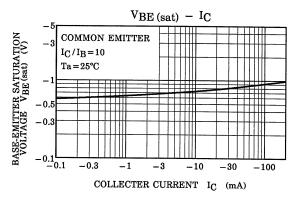
<sup>\*</sup> Total rating

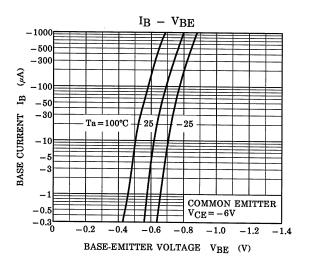
#### (Q1, Q2 Common)

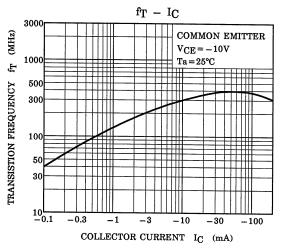


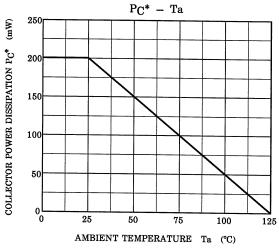












\* Total Rating

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20070701-EN GENERAL

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